December 1991 Revised December 1998 74ACTQ16543 16-Bit Registered Transceiver with 3-STATE Outputs

74ACTQ16543 16-Bit Registered Transceiver with 3-STATE Outputs

General Description

FAIRCHILD

SEMICONDUCTOR

The ACTQ16543 contains sixteen non-inverting transceivers containing two sets of D-type registers for temporary storage of data flowing in either direction. Each byte has separate control inputs which can be shorted together for full 16-bit operation. Separate Latch Enable and Output Enable inputs are provided for each register to permit independent input and output control in either direction of data flow.

The ACTQ16543 utilizes Fairchild Quiet Series[™] technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series[™] features GTO[™] output control and undershoot corrector for superior performance.

Features

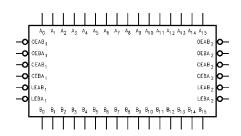
- Utilizes Fairchild FACT Quiet Series technology
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin output skew
- Independent registers for A and B buses
- Separate controls for data flow in each direction
 Back-to-back registers for storage
- Multiplexed real-time and stored data transfers
- Separate control logic for each byte
- 16-bit version of the ACTQ543
- Outputs source/sink 24 mA
- Additional specs for Multiple Output Switching
- Output loading specs for both 50 pF and 250pF loads

Ordering Code:

Order Number	Package Number	Package Description
74ACTQ16543SSC	MS56A	56-Lead Shrink Small Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACTQ16543MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Descriptions
OEAB	A-to-B Output Enable Input (Active LOW)
OEBAn	B-to-A Output Enable Input (Active LOW)
CEAB _n	A-to-B Enable Input (Active LOW)
CEBAn	B-to-A Enable Input (Active LOW)
LEAB _n	A-to-B Latch Enable Input (Active LOW)
LEBAn	B-to-A Latch Enable Input (Active LOW)
A ₀ -A ₁₅	A-to-B Data Inputs or
	B-to-A 3-STATE Outputs
B ₀ -B ₁₅	B-to-A Data Inputs or
	A-to-B 3-STATE Outputs

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74ACTQ16543

Connection Diagram

Pin Assignment	for	SSOP	and	TSSOP

OEAB, -	1	\bigcirc	56	- OEBA
LEAB	2		55	- LEBA
CEAB	3		54	CEBA
GND —	4		53	- GND
A0 -	5		52	— в _о
A1 -	6		51	— В1
v _{cc} —	7		50	— v _{cc}
A2 -	8		49	— в ₂
A3 —	9		48	— B ₃
A4 —	10		47	— В4
GND —	11		46	- GND
A5 —	12		45	— в ₅
А ₆ —	13		44	— в ₆
A7 —	14		43	— В ₇
A ₈ —	15		42	— в _а
A9 —	16		41	— B ₉
A ₁₀ —	17		40	— B ₁₀
gnd —	18		39	— GND
A _{1 1} —	19		38	— B ₁₁
A ₁₂ —	20		37	— B ₁₂
A ₁₃ —	21		36	— B ₁₃
v _{cc} —	22		35	— v _{cc}
A ₁₄ —	23		34	— В ₁₄
A ₁₅ —	24		33	— В ₁₅
GND —	25		32	— GND
CEAB ₂ —	26		31	- CEBA ₂
LEAB ₂	27		30	- LEBA2
OEAB ₂ —	28		29	- OEBA ₂
				I

Functional Description

The ACTQ16543 contains sixteen non-inverting transceivers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The following description applies to each byte. For data flow from A to B, for example, the A-to-B Enable $(\overline{\text{CEAB}}_n)$ input must be LOW in order to enter data from A_0-A_{15} or take data from B_0-B_{15} , as indicated in the Data I/O Control Table. With CEAB, LOW, a LOW signal on the A-to-B Latch Enable (LEABn) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the $\overline{\text{LEAB}}_n$ signal puts the A latches in the storage mode and their outputs no longer change with the A inputs. With \overline{CEAB}_n and \overline{OEAB}_n both LOW, the 3-STATE B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is similar, but using the \overline{CEBA}_n , $\overline{\mathsf{LEBA}}_n$ and $\overline{\mathsf{OEBA}}_n$ inputs.

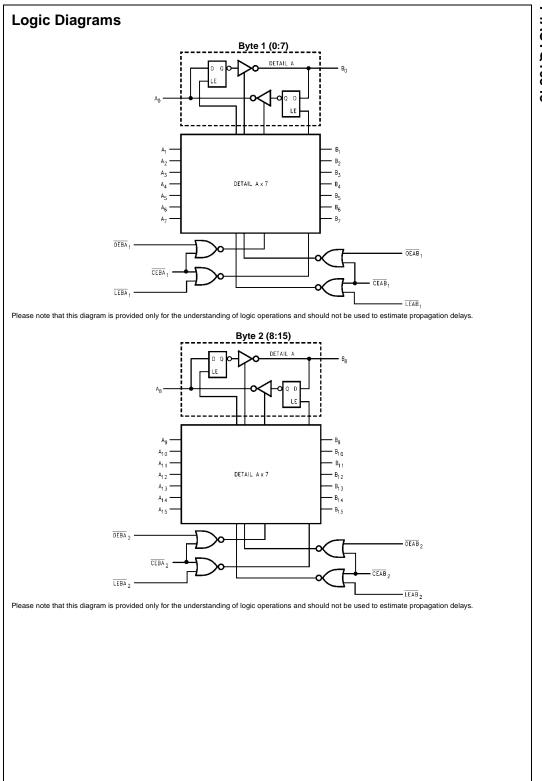
Data I/O Control Table

	Inputs		Latch Status	Output
CEAB _n	LEAB _n	$\overline{\text{OEAB}}_{n}$	(Byte n)	Buffers (Byte n)
Н	Х	Х	Latched	High Z
Х	н	Х	Latched	—
L	L	Х	Transparent	—
х	Х	н	—	High Z
L	Х	L		Driving

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial A-to-B data flow shown; B-to-A flow control

is the same, except using $\overline{\text{CEBA}}_n, \overline{\text{LEBA}}_n$ and $\overline{\text{OEBA}}_n$



74ACTQ16543

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Input Diode Current (IIK)	
$V_{I} = -0.5V$	–20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Output Diode Current (I _{OK})	
$V_{O} = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V _O)	–0.5V to V_{CC} + 0.5V
DC Output Source/Sink Current (I _O)	±50 mA
DC V _{CC} or Ground Current	
per Output Pin	±50 mA
Storage Temperature	-65°C to +150°C

Recommended Operating Conditions

Supply Voltage (V _{CC})	4.5V to 5.5V
Input Voltage (V _I)	0V to V_{CC}
Output Voltage (V _O)	0V to V_{CC}
Operating Temperature (T _A)	$-40^\circ C$ to $+85^\circ C$
Minimum Input Edge Rate ($\Delta V/\Delta t$)	125 mV/ns
V _{IN} from 0.8V to 2.0V	
V _{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	V _{cc}	T _A = +25°C		$T_A = -40^{\circ}C \text{ to}+85^{\circ}C$	Units	Conditions	
Symbol	Faiancici	(V)	Typ Gua		aranteed Limits	Units		
/ _{IH}	Minimum HIGH	4.5	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$	
	Input Voltage	5.5	1.5	2.0	2.0		or $V_{CC} - 0.1V$	
/ _{IL}	Maximum LOW	4.5	1.5	0.8	0.8	V	$V_{OUT} = 0.1V$	
	Input Voltage	5.5	1.5	0.8	0.8		or $V_{CC} - 0.1V$	
/ _{он}	Minimum HIGH	4.5	4.49	4.4	4.4	V	I _{OUT} = -50 μA	
	Output Voltage	5.5	5.49	5.4	5.4			
							$V_{IN} = V_{IL} or V_{IH}$	
		4.5		3.86	3.76	V	I _{OH} = -24 mA	
		5.5		4.86	4.76		I _{OH} = -24 mA (Note 2)	
/ _{OL}	Maximum LOW	4.5	0.001	0.1	0.1	V	I _{OUT} = 50 μA	
	Output Voltage	5.5	0.001	0.1	0.1			
							$V_{IN} = V_{IL} or V_{IH}$	
		4.5		0.36	0.44	V	I _{OL} = 24 mA	
		5.5		0.36	0.44		I _{OL} = 24 mA (Note 2)	
OZT	Maximum I/O	5.5		±0.5	±5.0	μA	$V_I = V_{IL}, V_{IH}$	
	Leakage Current						$V_{O} = V_{CC}, GND$	
IN	Maximum Input	5.5		±0.1	±1.0	μΑ	$V_I = V_{CC},$	
	Leakage Current						GND	
ССТ	Maximum I _{CC} /Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$	
сс	Max Quiescent	5.5		8.0	80.0	μΑ	$V_{IN} = V_{CC}$	
	Supply Current						or GND	
OLD	Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65V Max	
OHD	Output Current (Note 3)				-75	mA	V _{OHD} = 3.85V Min	
/ _{OLP}	Quiet Output	5.0	0.5	0.8		V	Figure 1, Figure 2	
	Maximum Dynamic V _{OL}						(Note 5)(Note 6)	
/ _{OLV}	Quiet Output	5.0	-0.5	-0.8		V	Figure 1, Figure 2	
	Minimum Dynamic V _{OL}						(Note 5)(Note 6)	
/ _{OHP}	Maximum	5.0	V _{OH} + 1.0	V _{OH} + 1.5		V	Figure 1, Figure 2	
	Overshoot						(Note 4)(Note 6)	
/ону	Minimum	5.0	V _{OH} - 1.0	V _{OH} – 1.8		V	Figure 1, Figure 2	
	V _{CC} Droop						(Note 4)(Note 6)	
/ _{IHD}	Minimum HIGH Dynamic	5.0	1.7	2.0		V	(Note 4)(Note 7)	
	Input Voltage Level							
/ _{ILD}	Maximum LOW Dynamic	5.0	1.2	0.8		V	(Note 4)(Note 7)	
	Input Voltage Level							

Note 4: Worst case package.

DC Electrical Characteristics (Continued)

Note 5: Maximum number of outputs that can switch simultaneously is n. (n - 1) outputs are switched LOW and one output held LOW. Note 6: Maximum number of outputs that can switch simultaneously is n. (n - 1) outputs are switched HIGH and one output held HIGH. Note 7: Maximum number of data inputs (n) switching. (n - 1) inputs switching 0V to 3V Input under test switching 3V to threshold (V_{ILD}) .

AC Electrical Characteristics

Symbol	Parameter	v _{cc} (V)	T _A = +25°C C _L = 50 pF			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_L = 50 \text{ pF}$		Units
		(Note 8)	Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay		3.8	5.9	8.3	3.0	9.0	
t _{PHL}	Transparent Mode	5.0	3.5	5.5	7.9	2.6	8.5	ns
	A _n to B _n or B _n to A _n							
t _{PLH}	Propagation Delay		4.7	6.9	9.8	3.4	10.8	
t _{PHL}	LEBA _n , LEAB _n	5.0	3.9	6.3	9.0	3.1	9.8	ns
	to A _n , B _n							
t _{PZH}	Output Enable Time		4.2	6.3	9.2	3.0	9.9	
t _{PZL}	\overline{OEBA}_n or \overline{OEAB}_n to A_n or B_n	5.0	4.9	7.3	10.3	3.6	10.3	ns
	\overline{CEBA}_n or \overline{CEAB}_n to A_n or B_n							
t _{PHZ}	Output Disable Time		2.8	5.2	8.0	2.1	8.3	
t _{PLZ}	\overline{OEBA}_n or \overline{OEAB}_n to A_n or B_n	5.0	2.6	5.0	7.6	2.0	8.1	ns
	$\overline{\text{CEBA}}_n$ or $\overline{\text{CEAB}}_n$ to A_n or B_n							

Note 8: Voltage Range 5.0 is 5.0V ± 0.5 V.

AC Operating Requirements

Symbol	Parameter	V _{CC} (V)	T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C C _L = 50 pF	Units
		(Note 9)	Тур	Guar	anteed Minimum	
t _S	Setup Time, HIGH or LOW	5.0		3.0	3.0	ns
	A_n or B_n to \overline{LEBA}_n or \overline{LEAB}_n					
t _H	Hold Time, HIGH or LOW	5.0		1.5	1.5	ns
	A_n or B_n to \overline{LEBA}_n or \overline{LEAB}_n					
t _W	Latch Enable, B to A	5.0		4.0	4.0	ns
	Pulse Width, LOW					

Note 9: Voltage Range 5.0 is 5.0V $\pm 0.5 V$

		T,	_A = -40 to +85	°C			
			V _{CC} = Com		T _△ = -40	to +85°C	
Symbol	Parameter		C _L = 50 pF		Vcc =	= Com	Units
0,		16 (Dutputs Switc	hina		250 pF	•
			(Note 10)	9	-	e 11)	
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	4.5		11.1	5.8	14.3	
t _{PHL}	Transparent Mode	3.7		9.6	5.1	13.4	ns
	A _n to B _n or B _n to A _n						
t _{PLH}	Propagation Delay	4.3		11.3	6.2	16.3	ns
t _{PHL}	\overline{LEBA}_{n} , \overline{LEAB}_{n} to A_{n} , B_{n}	3.7		9.7	5.8	14.9	
t _{PZH}	Output Enable Time	4.0		10.7			
t _{PZL}	\overline{OEBA}_n or \overline{OEAB}_n to A_n or B_n	4.3		11.3	(Note 12)		ns
	\overline{CEBA}_n or \overline{CEAB}_n to A_n or B_n						
t _{PHZ}	Output Disable Time	3.0		8.0			
t _{PLZ}	\overline{OEBA}_n or \overline{OEAB}_n to A_n or B_n	2.8		7.6	(Not	e 13)	ns
	\overline{CEBA}_n or \overline{CEAB}_n to A_n or B_n						
t _{OSHL}	Pin to Pin Skew			1.1			ns
(Note 14)	HL Data to Output						
t _{OSLH}	Pin to Pin Skew			1.4			ns
(Note 14)	LH Data to Output						
t _{OSHL}	Pin to Pin Skew			2.6			ns
(Note 14)	Latch to Output						
t _{OSLH}	Pin to Pin Skew			1.0			ns
(Note 14)	Latch to Output						
t _{OST}	Pin to Pin Skew			1.0			ns
(Note 14)	Data to Output						115
t _{OST}	Pin to Pin Skew			2.2			ns
(Note 14)	Latch to Output						

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all low-to-high, high-to-low, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: 3-STATE delays are load dominated and have been excluded from the datasheet.

Note 13: The Output Disable Time is dominated by the RC network (500Ω, 250 pF) on the output and has been excluded from the datasheet.

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}).

Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	$V_{CC} = 5.0V$
C _{PD}	Power Dissipation.Capacitance	95.0	pF	$V_{CC} = 5.0V$

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

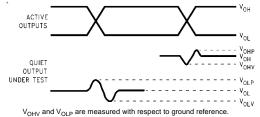
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

- 1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω .
- Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
- Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.



Input pulses have the following characteristics: f = 1 MHz, $t_r = 3$ ns, $t_f = 3$ ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

- Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.
- Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50 Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case for active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.
- VILD and VIHD:
- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level, V_{IH}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability on the measurements.

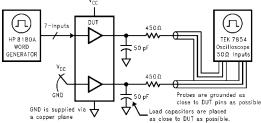


FIGURE 2. Simultaneous Switching Test Circuit

